MAX9150EUI Rev. A

RELIABILITY REPORT

FOR

MAX9150EUI

PLASTIC ENCAPSULATED DEVICES

August 6, 2001

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

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Conclusion

The MAX9150 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX9150 low-jitter, 10-port, low-voltage differential signaling (LVDS) repeater is designed for applications that require high-speed data or clock distribution while minimizing power, space, and noise. The device accepts a single LVDS input and repeats the signal at 10 LVDS outputs. Each differential output drives a total of 50 ohms, allowing point-to-point distribution of signals on transmission lines with 100 ohms terminations on each end.

Ultra-low 120ps (max) peak-to-peak jitter (deterministic and random) ensures reliable communication in high-speed links that are highly sensitive to timing error, especially those incorporating clock-and-data recovery, or serializers and deserializers. The high-speed switching performance guarantees 400Mbps data rate and less than 100ps skew between channels while operating from a single +3.3V supply.

Supply current at 400Mbps is 160mA (max) and is reduced to 60μ A (max) in low-power shutdown mode. Inputs and outputs conform to the EIA/TIA-644 LVDS standard. A fail-safe feature sets the outputs high when the input is undriven and open, terminated, or shorted. The MAX9150 is available in a 28-pin TSSOP package

B. Absolute Maximum Ratings

Item	Rating
VCC to GND	-0.3V to +4V
RIN+, RIN- to GND	-0.3V to +4V
PWRDN to GND	-0.3V to (VCC + 0.3V)
DO_+, DO	-0.3V to +4V
Short-Circuit Duration	Continous
Junction Temperature	+150°C
Storage Temp.	-65°C to +150°C
Lead Temp. (10 sec.)	+300°C
Power Dissipation	
28-Pin TSSOP	1026mW
Derates above +70°C	
28-Pin TSSOP	12.8 mW/°C

II. Manufacturing Information

A.	Description/Function:	Low Supply Current, Step-Up DC-DC Converter
B.	Process: TC35 (0.35 M	licron Poly Gate Process)
C.	Number of Device Tran	sistors: 11,117
D.	Fabrication Location:	Taiwan
E.	Assembly Location:	Philippines
F.	Date of Initial Production	on: October, 2000

III. Packaging Information

A. Package Type:	28-Lead TSSOP
B. Lead Frame:	Copper
C. Lead Finish:	Solder Plate
D. Die Attach:	Silver-filled Epoxy
E. Bondwire:	Gold (1.0 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	Buildsheet # 05-2801-0008
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard JESD22-A112:	Level 1

IV. Die Information

A. Dimensions:	57 x 103	3 mils
B. Passivation:	Si ₃ N ₄ /S	iO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect: Al/Cu/Si/Ti		
D. Backside Metallization: None		
E. Minimum Metal	Width:	0.35 microns (as drawn)
F. Minimum Metal Spacing: 0.35 microns (as drawn)		
G. Bondpad Dimer	sions:	5 mil. Sq.
H. Isolation Dielect	tric:	SiO ₂

I. Die Separation Method: Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts:	Jim Pedicord	(Reliability Lab Manager)
	Bryan Preeshl	(Executive Director of QA)
	Kenneth Huening	(Vice President)

- B. Outgoing Inspection Level:0.1% for all electrical parameters guaranteed by the Datasheet.0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \frac{1}{\text{MTTF}} = \frac{1.83 \quad (\text{Chi square value for MTTF upper limit})}{192 \text{ x } 4389 \text{ x } 45 \text{ x } 2}$ Temperature Acceleration factor assuming an activation energy of 0.8eV

 $\lambda = 24.1 \text{ x } 10^{-9}$ $\lambda = 24.1 \text{ F.I.T.}$ (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The attached Burn-In Schematic (Spec. # 06-5618) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1L**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The HS07 die type has been found to have all pins able to withstand a transient pulse of ± 1500 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 250 mA and/or ± 20 V.

Table 1 Reliability Evaluation Test Results

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	(Note 1)		15	0
	Ta = 135 °C Biased Time = 192 hrs.	DC Parameters & functionality	45	0
Moisture Testin	ig (Note 2)			
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality	44	0
Mechanical Stre	ess (Note 2)			
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters	77	0

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Note 1: Life Test Data may represent plastic D.I.P. qualification lots for the Small Outline package. Note 2: Generic Process/Package data

Attachment #1

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V_{PS1} <u>3/</u>	All V_{PS1} pins
2.	All input and output pins	All other input-output pins

TABLE II. <u>Pin combination to be tested.</u> 1/2/

- 1/ Table II is restated in narrative form in 3.4 below.
- $\overline{2}$ No connects are not to be tested.
- $\overline{3/}$ Repeat pin combination I for each named Power supply and for ground (e.g., where V_{PS1} is V_{DD}, V_{CC}, V_{SS}, V_{BB}, GND, +V_S, -V_S, V_{REF}, etc).

3.4 <u>Pin combinations to be tested.</u>

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{SS3} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



Mil Std 883D Method 3015.7 Notice 8





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